Uni- and Bipolar Hall IC Switches for Magnetic Field Applications

# TLE4905G TLE4935G TLE4935-2G TLE4945-2G

# Sensors



Never stop thinking.

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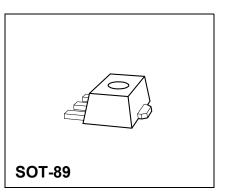


# Uni- and Bipolar Hall IC Switches for Magnetic Field Applications

# TLE4905G; TLE4935G; TLE4935-2G; TLE4945-2G

# Features

- Digital output signal
- · For unipolar and alternating magnetic fields
- Large temperature range
- Temperature compensated magnetic performance
- Protection against reversed polarity
- Output protection against electrical disturbances



Туре	Marking	Ordering Code	Package
TLE4905G	05	Q62705-K402	SOT-89
TLE4935G	35	Q62705-K404	SOT-89
TLE4935-2G	35 2	Q62705-K405	SOT-89
TLE4945-2G	45 2	Q62705-K403	SOT-89

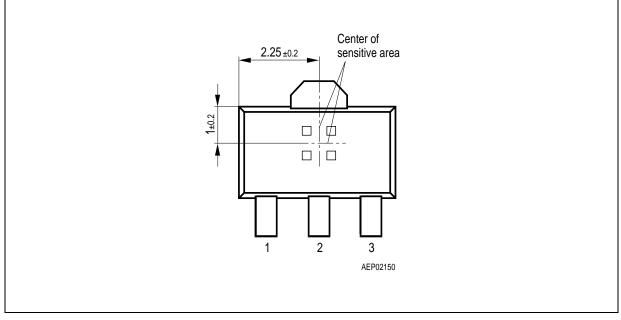
TLE4905/35/35-2/45-2 (Unipolar/Bipolar Magnetic Field Switches) have been designed specifically for automotive and industrial applications. Reverse polarity protection is included on-chip as is output protection against negative voltage transients.

Typical applications are position/proximity indicators, brushless DC motor commutation, rotational indexing etc.



# **Pin Configuration**

(view on branded side of component)



# Figure 1

# **Pin Definitions and Funtions**

Pin No.	Symbol	Function
1	Vs	Supply voltage
2	GND	Ground
3	Q	Output



# **Circuit Description**

The circuit includes Hall generator, amplifier and Schmitt-Trigger on one chip. The internal reference provides the supply voltage for the components. A magnetic field perpendicular to the chip surface induces a voltage at the hall probe. This voltage is amplified and switches a Schmitt-trigger with open-collector output. A protection diode against reverse power supply is integrated. The output is protected against electrical disturbances.

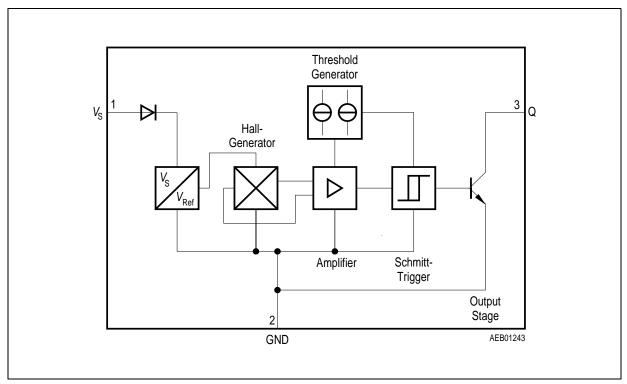


Figure 2 Block Diagram



# Functional Description Unipolar Type TLE4905 (Figure 3 and 4)

When a positive magnetic field is applied in the indicated direction (**Figure 3**) and the turn-on magnetic induction  $B_{OP}$  is exceeded, the output of the Hall-effect IC will conduct (Operate Point). When the magnetic field is reduced to a value smaller than the release point, the output of the IC turns off (Release Point; **Figure 4**).

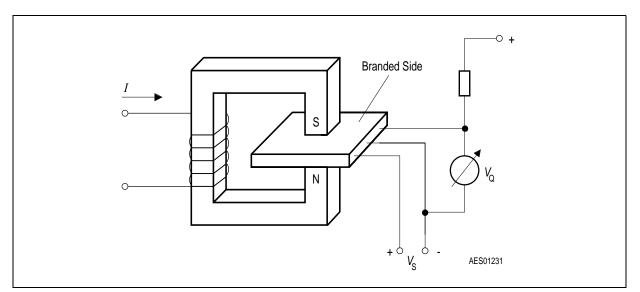


Figure 3 Sensor/Magnetic-Field Configuration

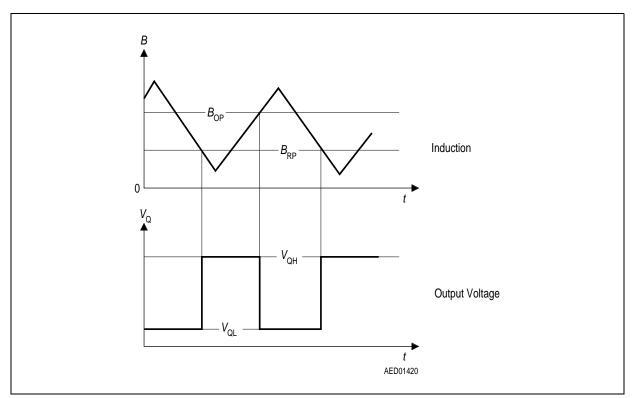


Figure 4 Switching Characteristics Unipolar Type

Data Sheet



# Functional Description Bipolar Type TLE4935/35-2/45-2 (Figure 5 and 6)

When a positive magnetic field is applied in the indicated direction (**Figure 5**) and the turn-on magnetic induction  $B_{OP}$  is exceeded, the output of the Hall-effect IC will conduct (Operate Point). The output state does not change unless a reverse magnetic field exceeding the turn-off magnetic induction  $|B_{RP}|$  is exceeded. In this case the output will turn off (Release Point; **Figure 6**).

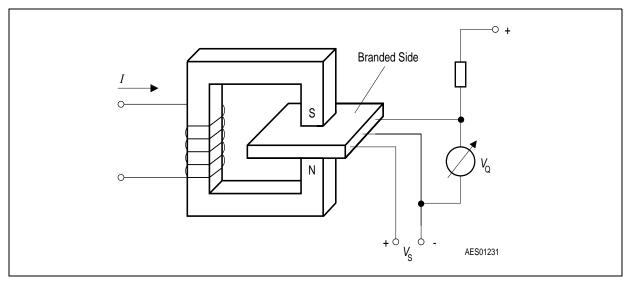


Figure 5 Sensor/Magnetic-Field Configuration

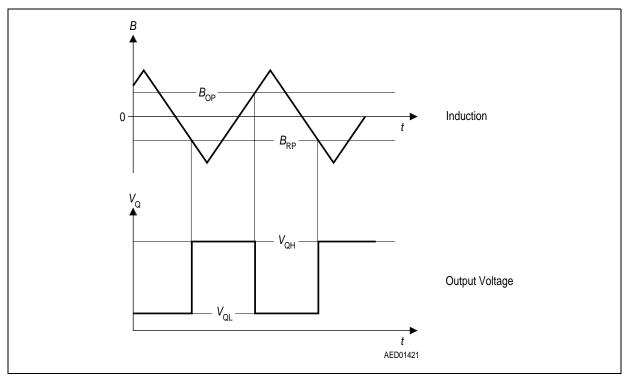
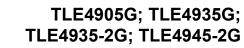


Figure 6 Switching Characteristics Bipolar Type





# **Absolute Maximum Ratings**

 $T_{\rm i}$  = - 40 to 150 °C

Parameter	Symbol	Limit	Values	Unit	Remarks
		min.	max.		
Supply voltage	Vs	- 40	32	V	_
Supply voltage	Vs	-	40	V	<i>t</i> < 400 ms; v = 0.1
Output voltage	VQ	-	32	V	-
Output current	I <sub>Q</sub>	-	100	mA	-
Output reverse current	$-I_{Q}$	-	100	mA	-
Junction temperature	Tj	- 40	150	°C	-
Storage temperature	$T_{\rm stg}$	- 50	150	°C	_
Thermal resistance	$R_{ m th~JA}$	_	100	K/W	-

Note: Stresses above those listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

# **Operating Range**

Parameter	Symbol	Limit	Limit Values		Remarks
		min.	max.		
Supply voltage	Vs	4.0	24	V	-
Junction temperature	Tj	- 40	150	°C	-

Note: In the operating range the functions given in the circuit description are fulfilled.



# **AC/DC Characteristics**

Parameter	Symbol	Lir	nit Val	ues	Unit	<b>Test Condition</b>	Test
		min.	typ.	max.			Circuit
Supply current	Ι	1.6	—	5.0	mA		1
	$I_{\mathrm{SHigh}}$	_	2.5	_	mA	$B < B_{RP}$	1
	I <sub>SLow</sub>	-	3.5	-	mA	$B < B_{RP} \\ B > B_{OP}$	1
Output saturation voltage	V <sub>QSat</sub>	-	0.25	0.5	V	<i>I</i> <sub>Q</sub> = 40 mA	1
Output leakage current	I <sub>QL</sub>	-	-	10	μA	V <sub>Q</sub> = 18 V	1
Rise/fall time	<i>t</i> <sub>r</sub> / <i>t</i> <sub>f</sub>	-	-	1	μS	$R_{\rm L}$ = 1.2 k $\Omega$ $C_{\rm L} \le$ 33 pF	1

Note: The listed characteristics are ensured over the operating range of the integrated circuit. Typical characteristics specify mean values expected over the production spread. If not otherwise specified, typical characteristics apply at  $T_j = 25^{\circ}$ C and the given supply voltage.



### **Magnetic Characteristics**

 $4.0 \text{ V} \le V_{\text{S}} \le 24 \text{ V}$ 

Parameter Sy	Symbol		Limit Values									
			4905 oolar		4935 ar latch		1935-2 ar latch	bip	l945-2 olar itch	-		
		min.	max.	min.	max.	min.	max.	min.	max.			

# Junction Temperature $T_j = -40 \ ^{\circ}C$

Turn-ON										
induction	B <sub>OP</sub>	7.5	19	10	20	15	27	- 3	6	mT
Turn-OFF										
induction	B <sub>RP</sub>	5.5	17	- 20	– 10	- 27	– 15	- 6	3	mT
Hysteresis										
$(B_{OP}-B_{RP})$	$\Delta B_{H}$	2	6.5	20	40	30	54	1	5	mT

### Junction Temperature $T_i = 25 \degree C$

Turn-ON										
induction	B <sub>OP</sub>	7	18	10	20	14	26	- 3	6	mT
Turn-OFF										
induction	B <sub>RP</sub>	5	16	- 20	– 10	- 26	– 14	- 6	3	mT
Hysteresis										
$(B_{OP}-B_{RP})$	$\Delta B_{H}$	2	6	20	40	28	52	1	5	mT

# Junction Temperature $T_i = 85 \degree C$

Turn-ON										
induction	B <sub>OP</sub>	6.5	17.5	10	20	13	26	- 3	6	mT
Turn-OFF	-									
induction	B <sub>RP</sub>	4.5	15	- 20	- 10	- 26	– 13	- 6	3	mT
Hysteresis										
$(B_{OP}-B_{RP})$	$\Delta B_{\rm H}$	2	5.5	20	40	26	52	1	5	mT

### Junction Temperature T<sub>i</sub> = 150 °C

Turn-ON										
induction	B <sub>OP</sub>	6	17	10	20	12	25	- 3	6	mΤ
Turn-OFF										
induction	B <sub>RP</sub>	4	14	- 20	– 10	- 25	– 12	- 6	3	mT
Hysteresis										
$(B_{OP}-B_{RP})$	$\Delta B_{H}$	2	5	20	40	24	50	1	5	mT

Note: The listed characteristics are ensured over the operating range of the integrated circuit. Typical characteristics specify mean values expected over the production spread. If not otherwise specified, typical characteristics apply at  $T_i = 25^{\circ}$ C and the given supply voltage.



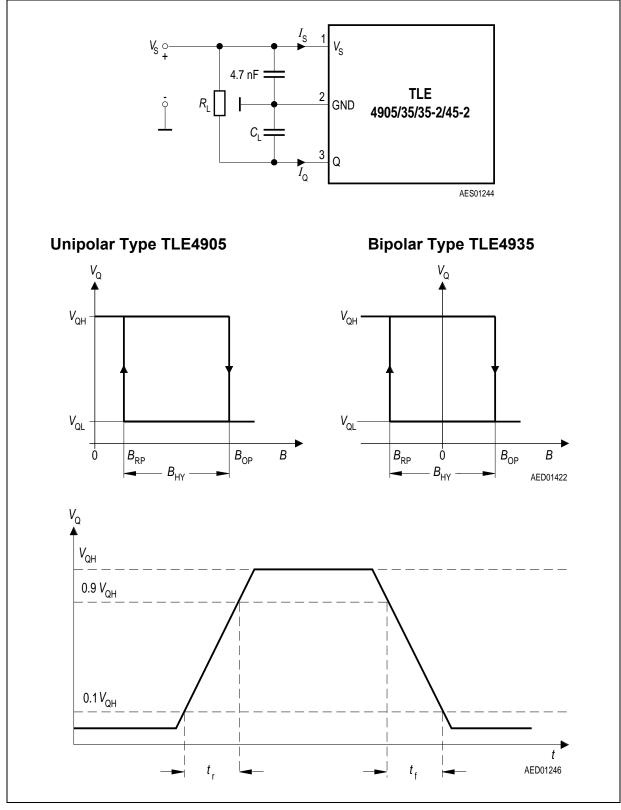


Figure 7 Test Circuit 1



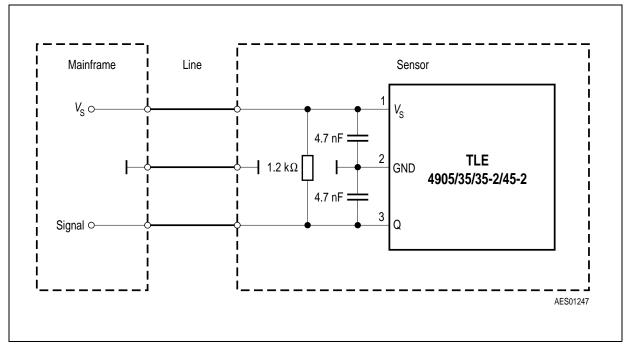
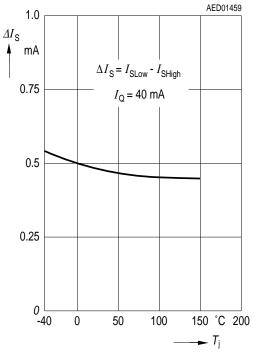


Figure 8 Application Circuit

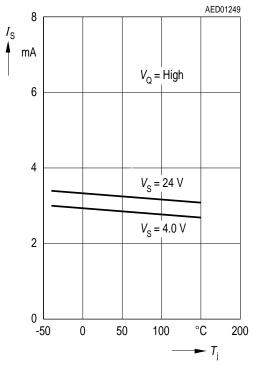


If not otherwise specified, all curves reflect typical values at  $T_i$  = 25 °C and  $V_s$  = 12 V **Quiescent Current Difference Saturation Voltage versus** 

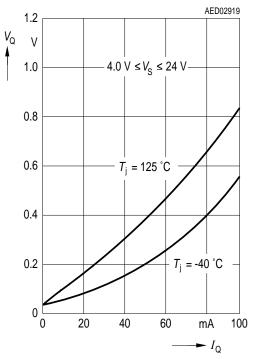
# versus Temperature



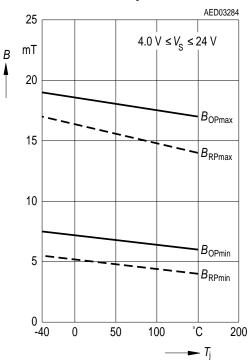
# **Quiescent Current versus Junction Temperature**







# **TLE4905** Operate-and Release-Point versus Junction Temperature

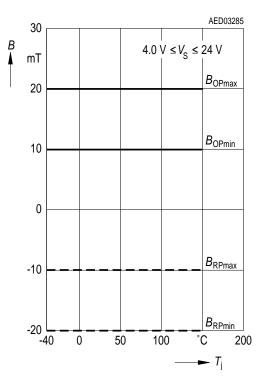


Data Sheet

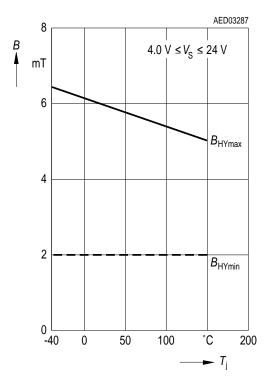
V1.2, 2004-06-07



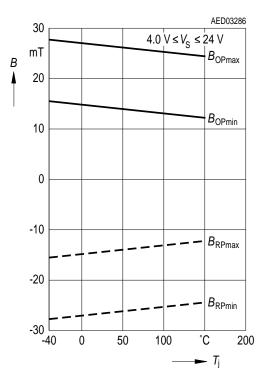
# TLE4935 Operate-and Release-Point versus Junction Temperature



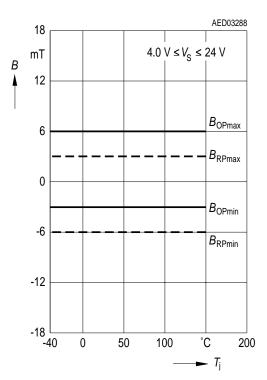
# TLE4905 Hysteresis versus Junction Temperature







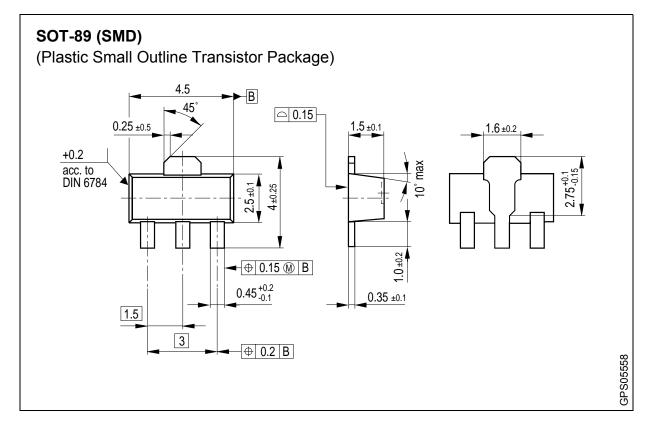
# TLE4945-2 Operate-and Release-Point versus Junction Temperature



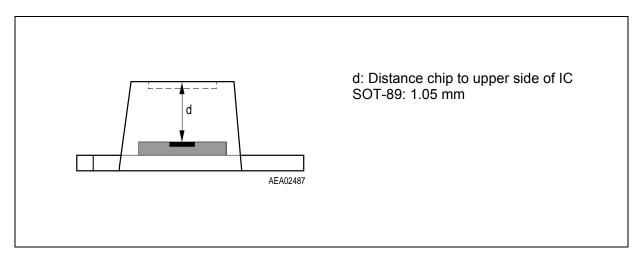
Data Sheet



# Package Outlines



## **Package Information**



# Sorts of Packing

Package outlines for tubes, trays etc. are contained in our data book "Package Information". SMD = Surface Mounted Device

Dimensions in mm

Downloaded from Elcodis.com electronic components distributor



Revisio	on History:2004-06-07, V1.2
Previous	Version: 2004-03-19, V1.1
Page	Subjects (major changes since last revision)
13,14	typical curves removed
-	new format of data sheet

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